

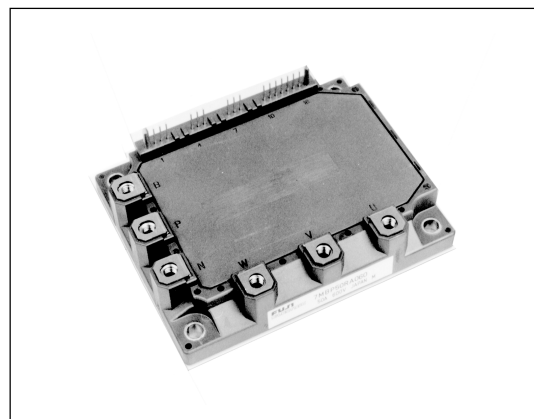
7MBP150RTB060

IPM-R3 series

600V / 150A 7 in one-package

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



Maximum ratings and characteristics

- Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item	Symbol	Rating		Unit		
		Min.	Max.			
Bus voltage (between terminal P and N)	DC	Vdc	0	450	V	
	Surge	VDC(surge)	0	500	V	
	Shortoperating	Vsc	200	400	V	
Collector-Emitter voltage	Vces *1	0	600	V		
Inverter	Collector current	DC	Ic	-	150	A
		1ms	IcP	-	300	A
		Duty=68.2%	Ic *2	-	150	A
Collector power dissipation	One transistor	Pc *3	-	431	W	
Brake	Collector current	DC	Ic	-	50	A
		1ms	IcP	-	100	A
	Forward Current of Diode		If	-	50	A
Collector power dissipation	One transistor	Pc *3	-	198	W	
Input voltage of power supply for Pre-Driver	Vcc *4	-0.5	20	V		
Input signal voltage	Vin *5	-0.5	Vcc+0.5	V		
Input signal current	Iin	-	3	mA		
Alarm signal voltage	VALM *6	-0.5	Vcc	V		
Alarm signal current	IALM *7	-	20	mA		
Junction temperature	Tj	-	150	°C		
Operating case temperature	Tcp	-20	100	°C		
Storage temperature	Tsig	-40	125	°C		
Isolating voltage (Case-Terminal)	Viso *8	-	AC2.5	kV		
Screw torque	Mounting (M5)	-	3.5 *9	N·m		
	Terminal (M5)	-	3.5 *9	N·m		

Note

- *1 : Vces shall be applied to the input voltage between terminal P and U or V or W or DB, N and U or V or W or DB.
- *2 : $125^{\circ}\text{C}/\text{FWD Rth}(j-c)/(Ic \times V_F \text{ MAX})=125/0.47/(150 \times 2.6) \times 100=68.2\%$
- *3 : $Pc=125^{\circ}\text{C}/\text{IGBT Rth}(j-c)=125/0.29=431\text{W}$ [Inverter]
 $Pc=125^{\circ}\text{C}/\text{IGBT Rth}(j-c)=125/0.63=198\text{W}$ [Break]
- *4 : Vcc shall be applied to the input voltage between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.
- *5 : Vin shall be applied to the input voltage between terminal No. 2 and 1, 5 and 4, 8 and 7, 12,13,14,15 and 10.
- *6 : VALM shall be applied to the voltage between terminal No. 16 and 10.
- *7 : IALM shall be applied to the input current to terminal No. 16.
- *8 : 50Hz/60Hz sine wave 1 minute.
- *9 : Recommendable Value : 2.5 to 3.0 N·m

Weight

Item	Symbol	Min.	Typ.	Max.	Unit
Weight	Wt	-	450	-	g

- *9 : (For 1 device, Case is under the device)

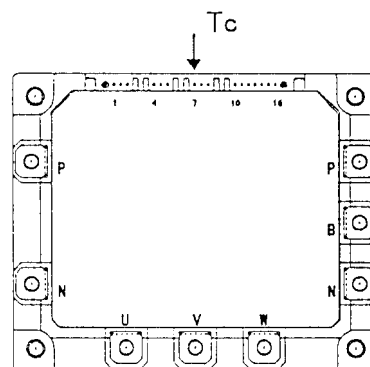


Fig.1 Measurement of case temperature

Electrical characteristics (at $T_c=T_j=25^{\circ}\text{C}$, $V_{cc}=15\text{V}$ unless otherwise specified.)

● Main circuit

Item		Symbol	Condition	Min.	Typ.	Max.	Unit	
Inverter	Collector current at off signal input	I_{CES}	$V_{CE}=600\text{V}$ V_{in} terminal open.	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_c=150\text{A}$	Terminal	-	-	2.3	V
				Chip	-	1.8	-	
	Forward voltage of FWD	V_F	$I_c=150\text{A}$	Terminal	-	-	2.6	V
Chip				-	1.6	-		
Brake	Collector current at off signal input	I_{CES}	$V_{CE}=600\text{V}$ V_{in} terminal open.	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_c=50\text{A}$	Terminal	-	-	2.2	V
				Chip	-	1.75	-	
	Forward voltage of Diode	V_F	$-I_c=50\text{A}$	Terminal	-	-	3.3	V
Chip				-	1.9	-		
Turn-on time	t_{on}	$V_{DC}=300\text{V}, T_j=125^{\circ}\text{C}$		1.2	-	-	μs	
Turn-off time	t_{off}	$I_c=150\text{A}$ Fig.1, Fig.6		-	-	3.6		
Reverse recovery time	t_{rr}	$V_{DC}=300\text{V}, I_c=150\text{A}$ Fig.1, Fig.6		-	-	0.3		
Maximum Avalanche Energy (A non-repetition)	P_{AV}	Internal wiring inductance=50nH Main circuit wiring inductance=54nH		170	-	-	mJ	

● Control circuit

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Supply current of P-line side pre-driver(one unit)	I_{ccp}	Switching Frequency : 0 to 15kHz $T_c=-20$ to 125°C Fig.7	-	-	18	mA
Supply current of N-line side pre-driver	I_{ccn}		-	-	65	mA
Input signal threshold voltage (on/off)	$V_{in(th)}$	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	V_Z	$R_{in}=20\text{k}\Omega$	-	8.0	-	V
Alarm signal hold time	t_{ALM}	$T_c=-20^{\circ}\text{C}$ Fig.2	1.1	-	-	ms
		$T_c=25^{\circ}\text{C}$ Fig.2	-	2.0	-	ms
		$T_c=125^{\circ}\text{C}$ Fig.2	-	-	4.0	ms
Limiting resistor for alarm	R_{ALM}		1425	1500	1575	Ω

● Protection Section ($V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Over Current Protection Level of Inverter circuit	I_{oc}	$T_j=125^{\circ}\text{C}$	225	-	-	A
Over Current Protection Level of brake circuit		$T_j=125^{\circ}\text{C}$	75	-	-	A
Over Current Protection Delay time	t_{DOC}	$T_j=125^{\circ}\text{C}$	-	5	-	μs
SC Protection Delay time	t_{SC}	$T_j=125^{\circ}\text{C}$ Fig.4	-	-	8	μs
IGBT Chip Over Heating	T_{jOH}	surface of IGBT chips	150	-	-	$^{\circ}\text{C}$
Over Heating Protection Hysteresis	T_{jH}		-	20	-	$^{\circ}\text{C}$
Over Heating Protection Temperature Level	T_{COH}	$V_{DC}=0\text{V}, I_c=0\text{A}$, Case temperature	110	-	125	$^{\circ}\text{C}$
Over Heating Protection Hysteresis	T_{CH}		-	20	-	$^{\circ}\text{C}$
Under Voltage Protection Level	V_{UV}		11.0	-	12.5	V
Under Voltage Protection Hysteresis	V_H		0.2	0.5	-	V

● Thermal characteristics($T_c=25^{\circ}\text{C}$)

Item			Symbol	Min.	Typ.	Max.	Unit
Junction to Case thermal resistance	INV	IGBT	$R_{th(j-c)}$	-	-	0.29	$^{\circ}\text{C/W}$
		FWD	$R_{th(j-c)}$	-	-	0.47	$^{\circ}\text{C/W}$
	Brake	IGBT	$R_{th(j-c)}$	-	-	0.63	$^{\circ}\text{C/W}$
Case to fin thermal resistance with compound			$R_{th(c-f)}$	-	0.05	-	$^{\circ}\text{C/W}$

● Noise Immunity ($V_{DC}=300\text{V}, V_{cc}=15\text{V}$, Test Circuit Fig.5)

Item	Condition	Min.	Typ.	Max.	Unit
Common mode rectangular noise	Pulse width $1\mu\text{s}$, polarity \pm , 10minuets Judge : no over-current, no miss operating	± 2.0	-	-	kV
Common mode lightning surge	Rise time $1.2\mu\text{s}$, Fall time $50\mu\text{s}$ Interval 20s, 10 times Judge : no over-current, no miss operating	± 5.0	-	-	kV

● Recommendable value

Item	Symbol	Min.	Typ.	Max.	Unit
DC Bus Voltage	V_{DC}	-	-	400	V
Operating Supply Voltage of Pre-Driver	V_{cc}	13.5	15.0	16.5	V
Screw torque (M5)	-	2.5	-	3.0	Nm

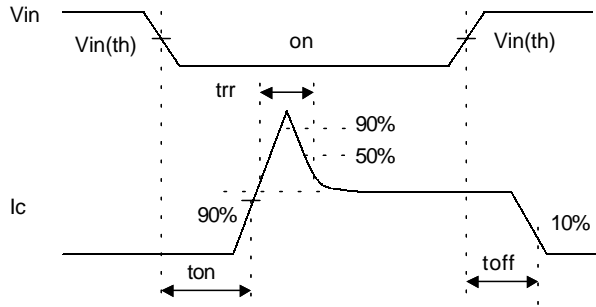
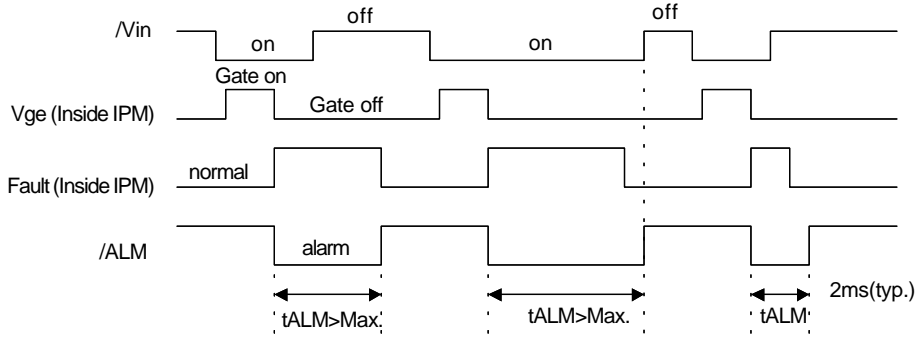


Figure 1. Switching Time Waveform Definitions



Fault : Over-current, Over-heat or Under-voltage

Figure 2. Input / Output Timing Diagram

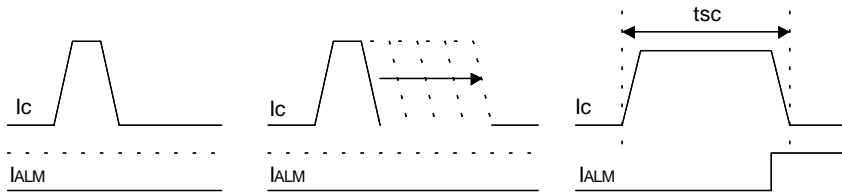


Figure 4 Definition of tsc

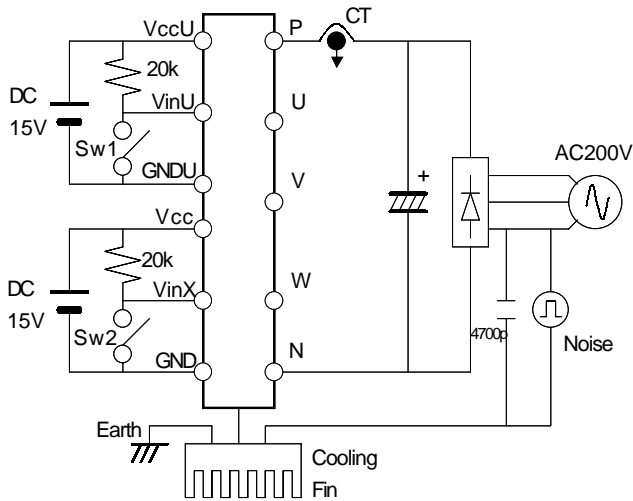


Figure 5. Noise Test Circuit

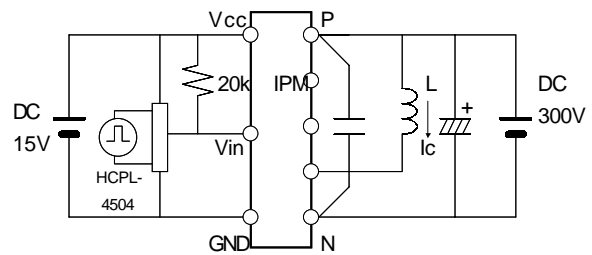


Figure 6. Switching Characteristics Test Circuit

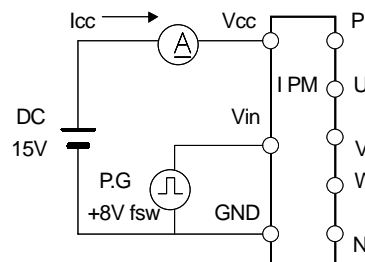
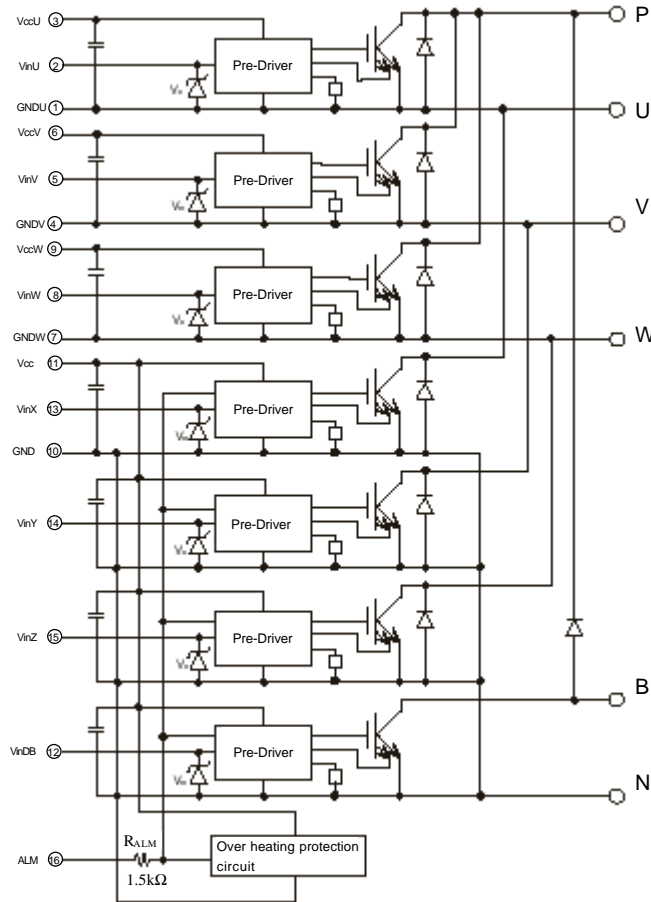


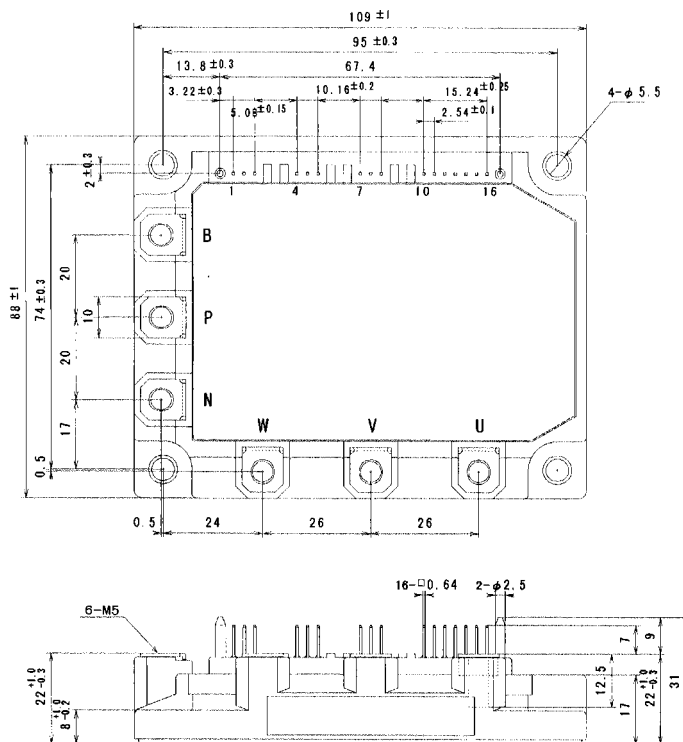
Figure 7. Icc Test Circuit

Block diagram



- Pre-driver include following functions
- ① Amplifier for drive
 - ② Short circuit protection
 - ③ Under voltage lockout circuit
 - ④ Over current protection
 - ⑤ IGBT chip over heating protection

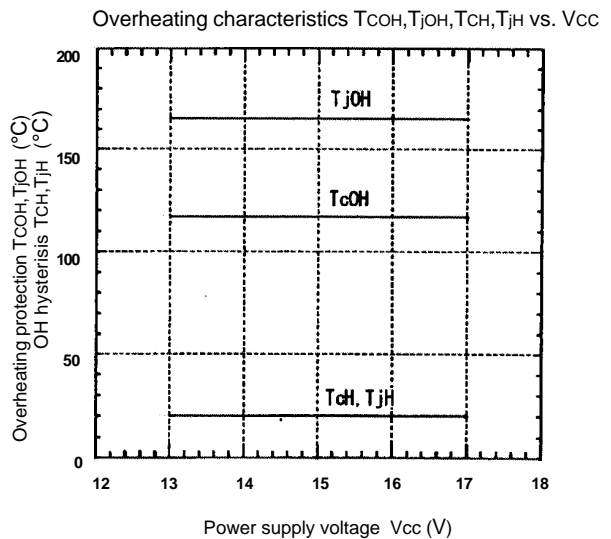
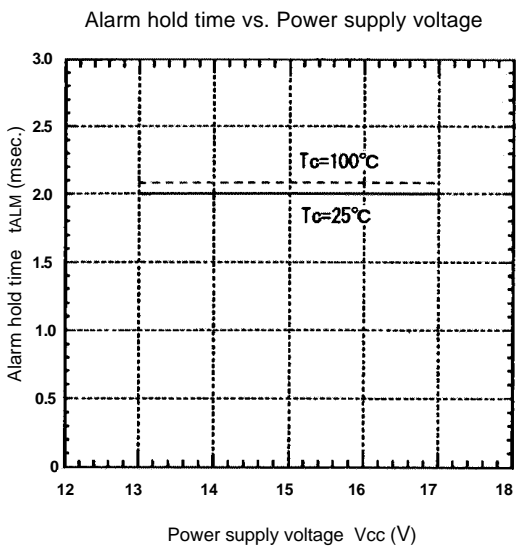
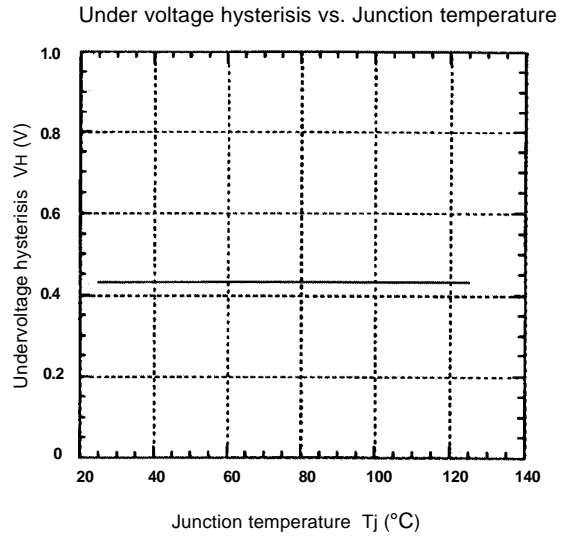
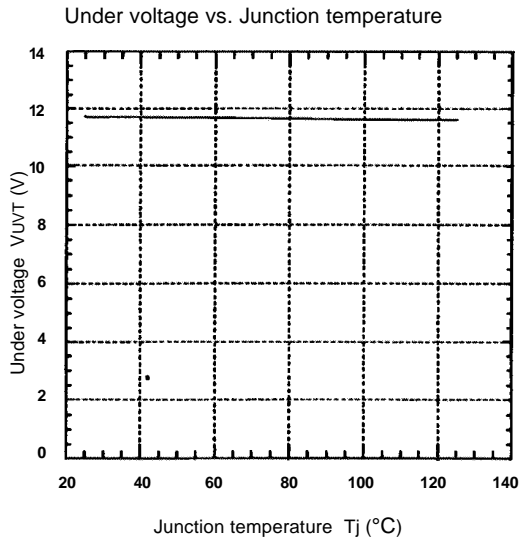
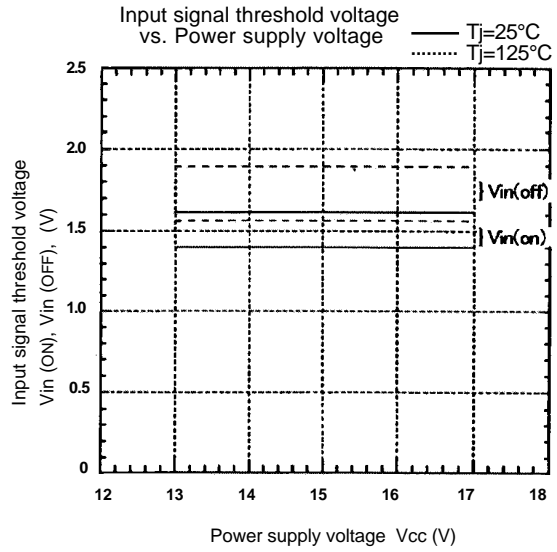
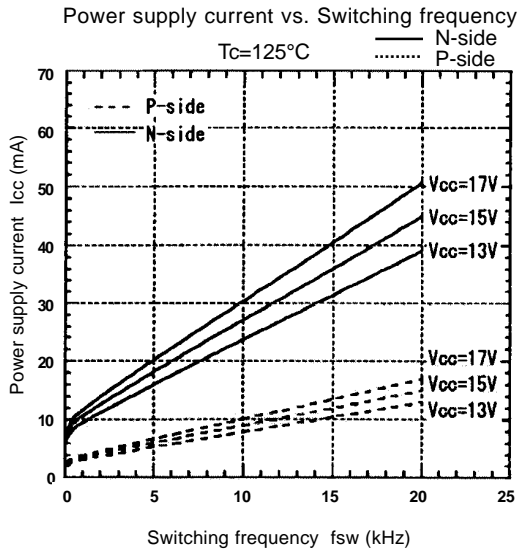
Outline drawings, mm



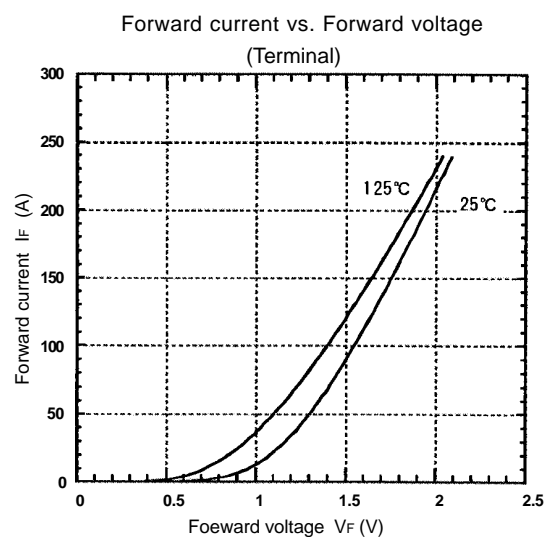
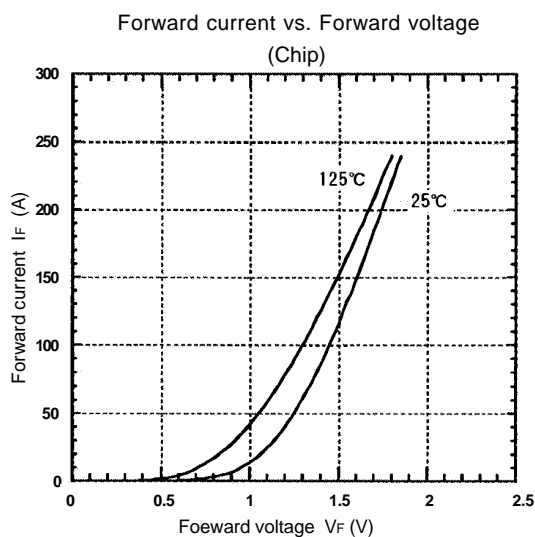
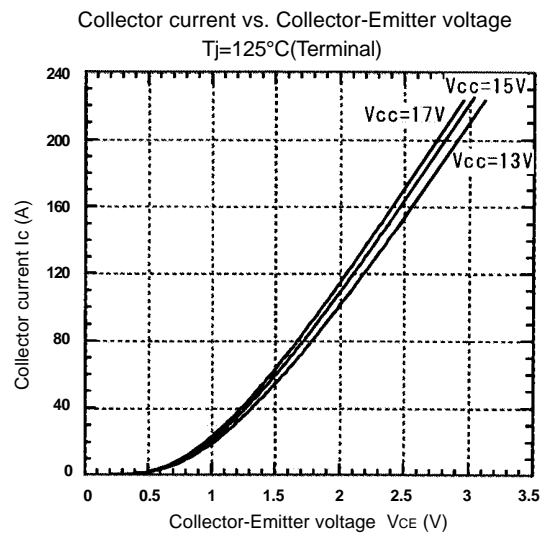
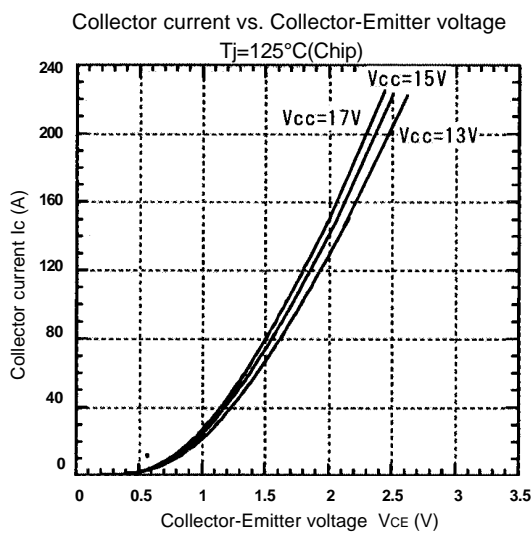
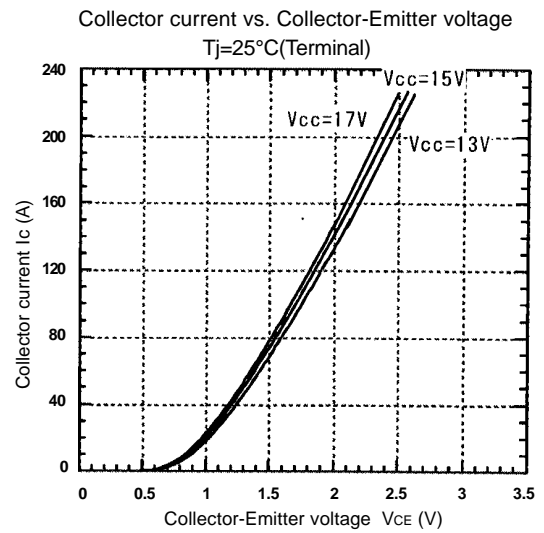
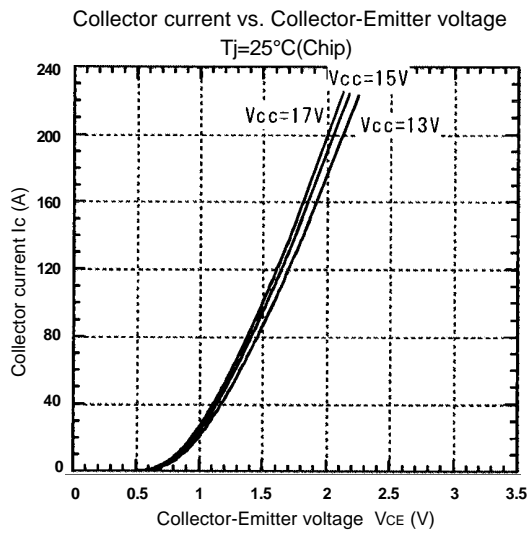
Mass : 450g

Characteristics

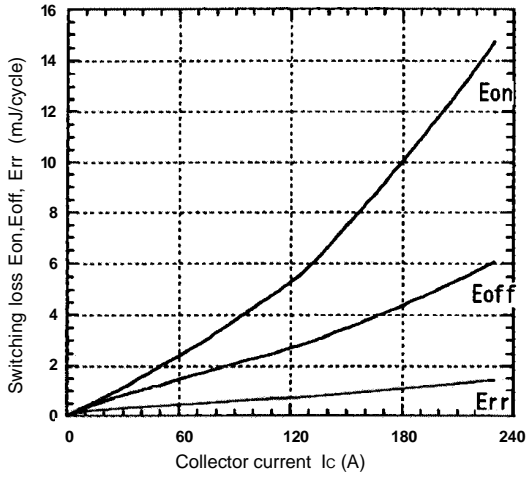
Control circuit characteristics (Representative)



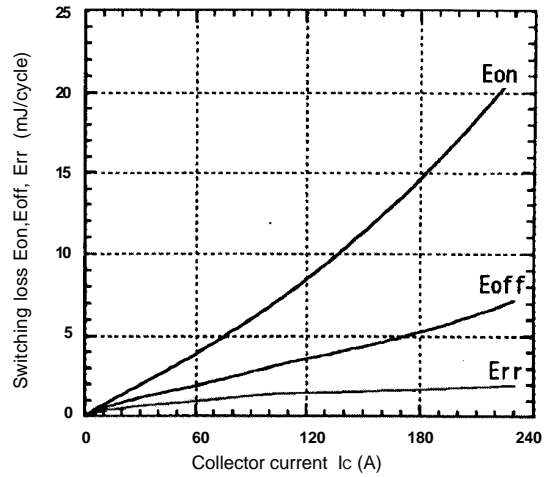
● Main circuit characteristics (Representative)



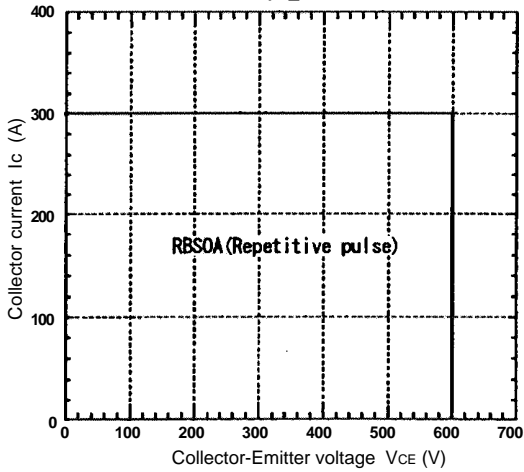
Switching Loss vs. Collector current
 $E_{dc}=300V, V_{cc}=15V, T_j=25^{\circ}C$



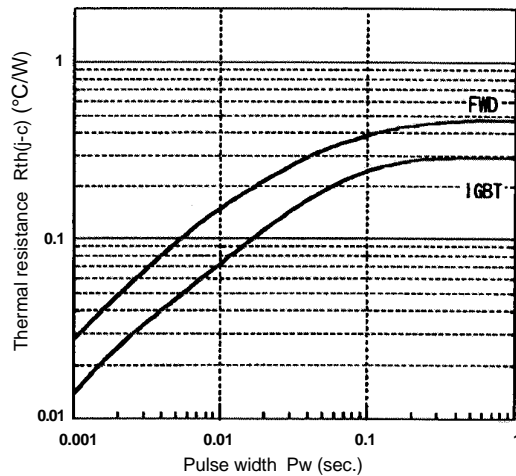
Switching Loss vs. Collector current
 $E_{dc}=300V, V_{cc}=15V, T_j=125^{\circ}C$



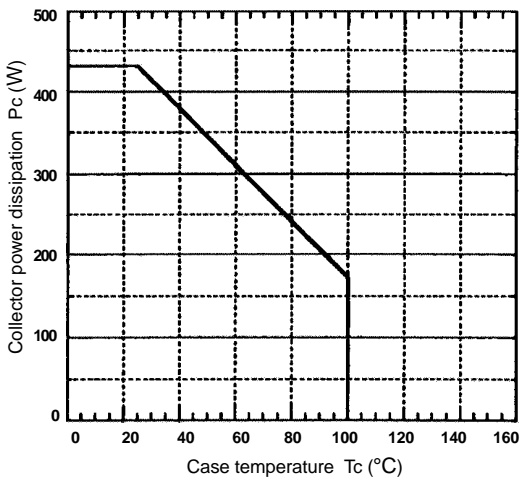
Reverse biased safe operating area
 $V_{cc}=15V, T_j \le 125^{\circ}C$



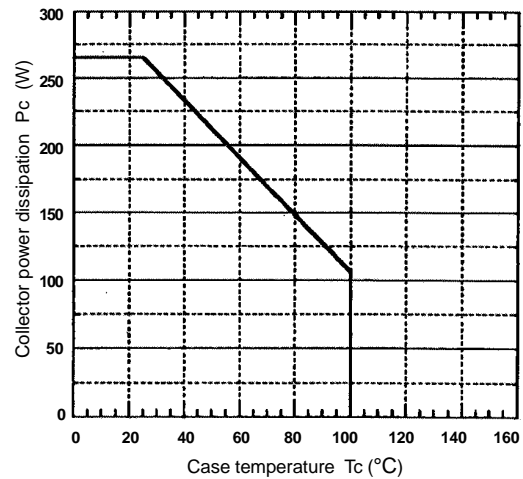
Transient thermal resistance

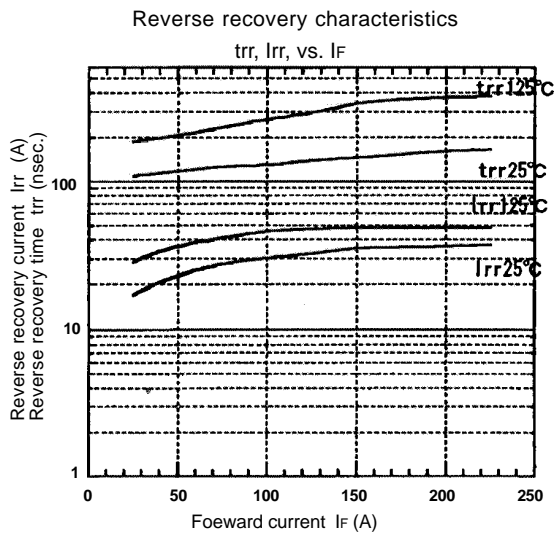
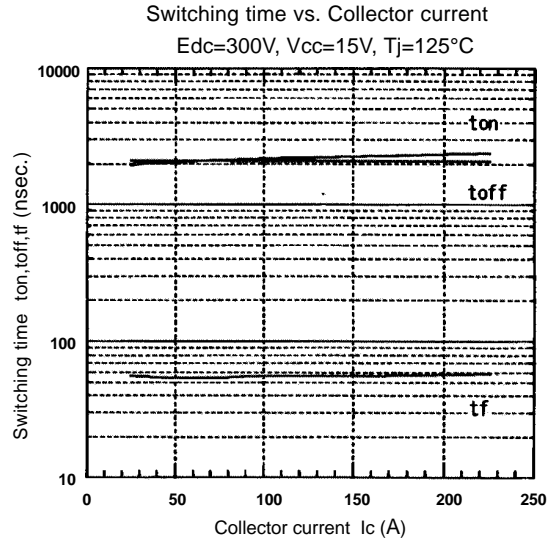
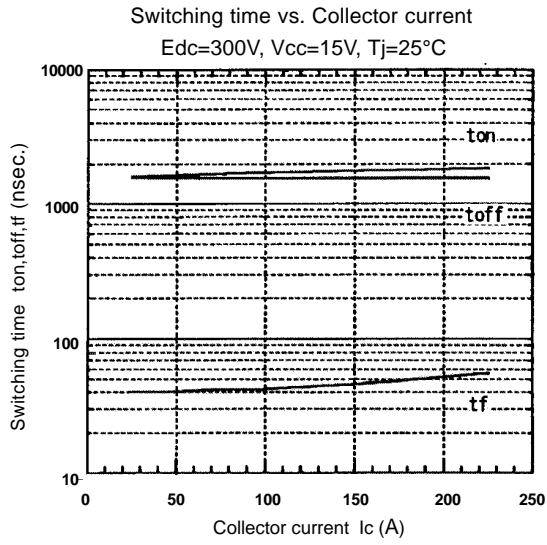


Power derating for IGBT (per device)



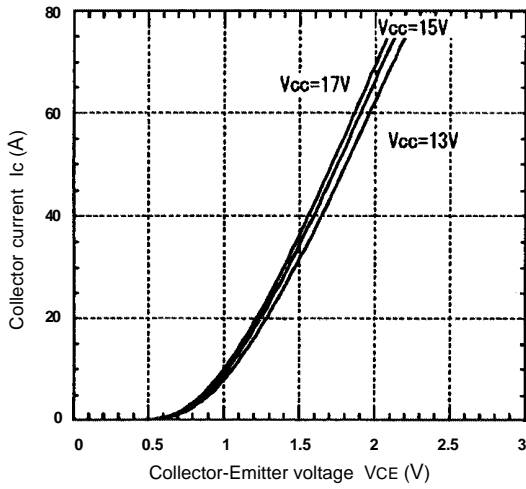
Power derating for FWD (per device)



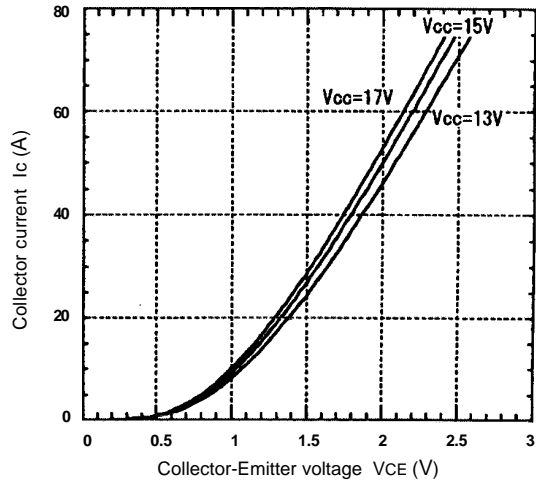


● Dynamic brake characteristics (Representative)

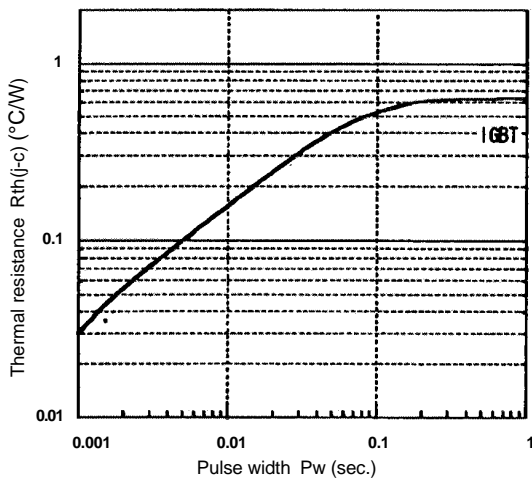
Collector current vs. Collector-Emitter voltage
T_j=25°C (Terminal)



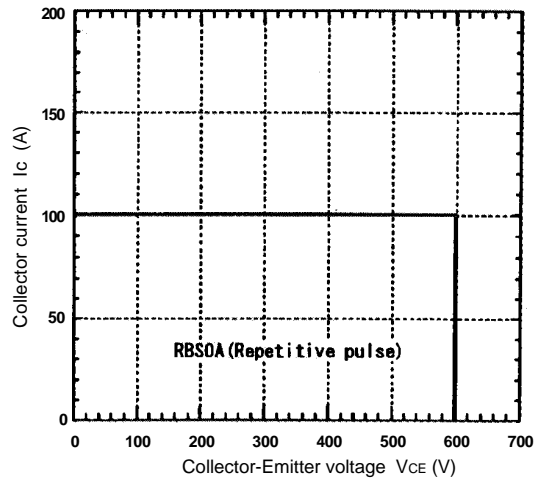
Collector current vs. Collector-Emitter voltage
T_j=125°C (Terminal)



Transient thermal resistance



Reverse biased safe operating area
V_{cc}=15V, T_j ≤ 125°C



Power derating for IGBT (per device)

